



# PJE8408

## 20V N-Channel Enhancement Mode MOSFET

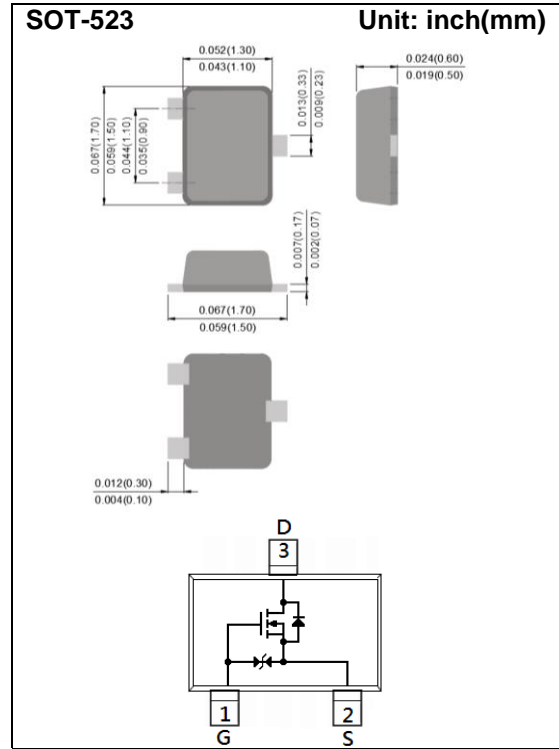
**Voltage** 20 V **Current** 500mA

### Features

- Low Voltage Drive (1.2V).
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### Mechanical Data

- Case : SOT-523 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.002 grams
- Marking : E08



### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage	V <sub>DS</sub>	20	V	
Gate-Source Voltage	V <sub>GS</sub>	±10	V	
Continuous Drain Current	I <sub>D</sub>	500	mA	
Pulsed Drain Current <sup>(Note 4)</sup>	I <sub>DM</sub>	1000	mA	
Power Dissipation	P <sub>D</sub>	T <sub>a</sub> =25°C	300	mW
		Derate above 25°C	2.4	mW/°C
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55~150	°C	
Typical Thermal Resistance	R <sub>θJA</sub>	417	°C/W	
- Junction to Ambient <sup>(Note 3)</sup>				



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## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	20	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	0.3	0.64	0.9	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =500mA	-	310	400	mΩ
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =200mA	-	360	650	
		V <sub>GS</sub> =1.8V, I <sub>D</sub> =100mA	-	430	800	
		V <sub>GS</sub> =1.5V, I <sub>D</sub> =50mA	-	510	1200	
		V <sub>GS</sub> =1.2V, I <sub>D</sub> =20mA	-	710	3000	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =16V, V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±8V, V <sub>DS</sub> =0V	-	±0.5	±10	uA
<b>Dynamic</b> <sup>(Note 5)</sup>						
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =10V, I <sub>D</sub> =500mA, V <sub>GS</sub> =4.5V <sup>(Note 1,2)</sup>	-	1.4	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	0.22	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	0.21	-	
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, f=1.0MHZ	-	67	-	pF
Output Capacitance	C <sub>oss</sub>		-	19	-	
Reverse Transfer Capacitance	C <sub>rss</sub>		-	6	-	
Turn-On Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> =10V, I <sub>D</sub> =150mA, V <sub>GS</sub> =4.0V, R <sub>G</sub> =10Ω <sup>(Note 1,2)</sup>	-	2.8	-	ns
Turn-On Rise Time	t <sub>r</sub>		-	20	-	
Turn-Off Delay Time	t <sub>d(off)</sub>		-	23	-	
Turn-Off Fall Time	t <sub>f</sub>		-	23	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	I <sub>s</sub>	---	-	-	500	mA
Diode Forward Voltage	V <sub>SD</sub>	I <sub>s</sub> =500mA, V <sub>GS</sub> =0V	-	0.87	1.3	V

**NOTES :**

1. Pulse width ≤ 300us, Duty cycle ≤ 2%
2. Essentially independent of operating temperature typical characteristics.
3. R<sub>θJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.
5. Guaranteed by design, not subject to production testing.



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## TYPICAL CHARACTERISTIC CURVES

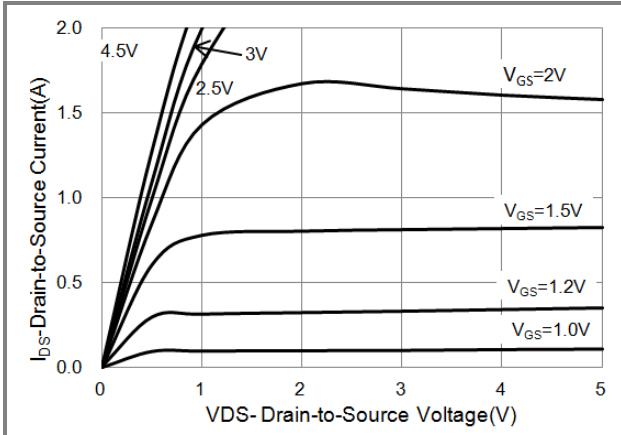


Fig.1 On-Region Characteristics

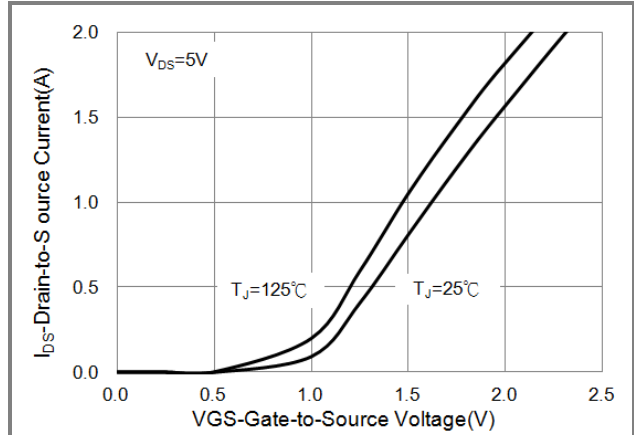


Fig.2 Transfer Characteristics

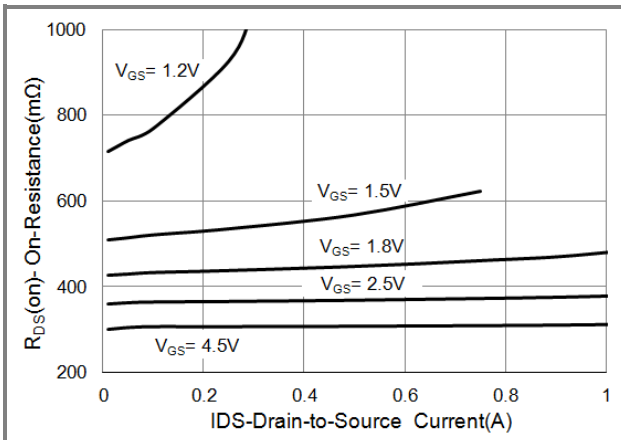


Fig.3 On-Resistance vs. Drain Current

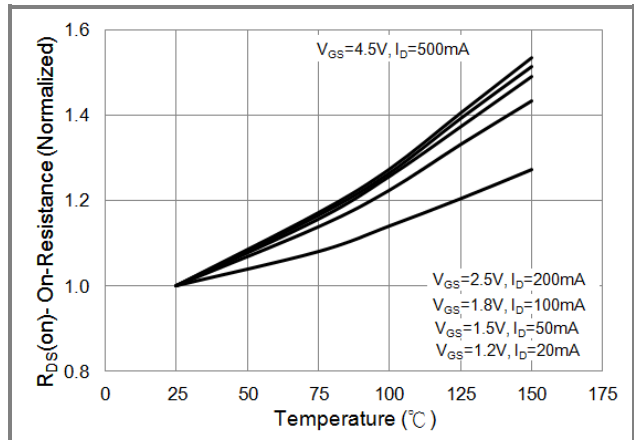


Fig.4 On-Resistance vs. Junction temperature

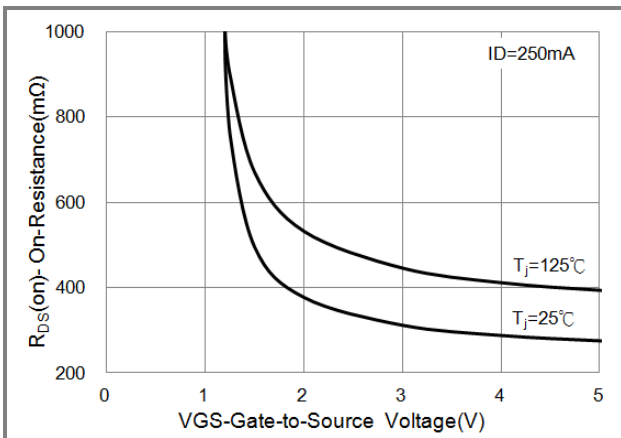


Fig.5 On-Resistance Variation with VGS.

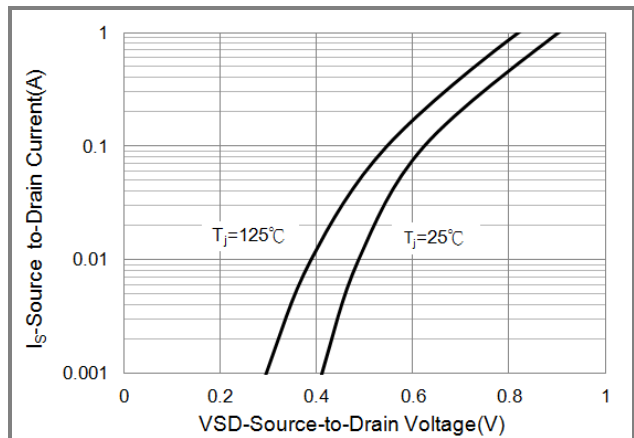


Fig.6 Body Diode Characteristics



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## TYPICAL CHARACTERISTIC CURVES

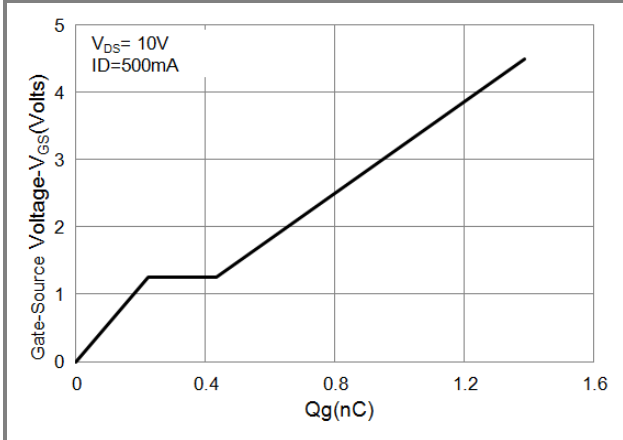


Fig.7 Gate-Charge Characteristics

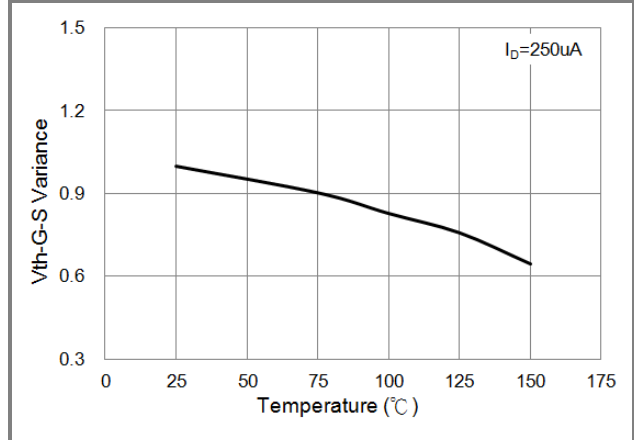


Fig.8 Threshold Voltage Variation with Temperature.

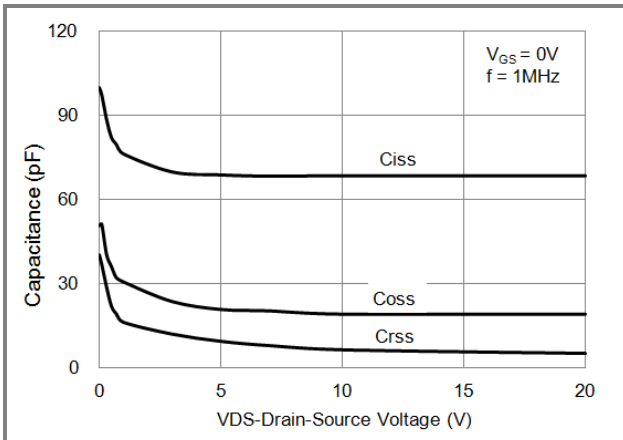


Fig.9 Capacitance vs. Drain-Source Voltage.

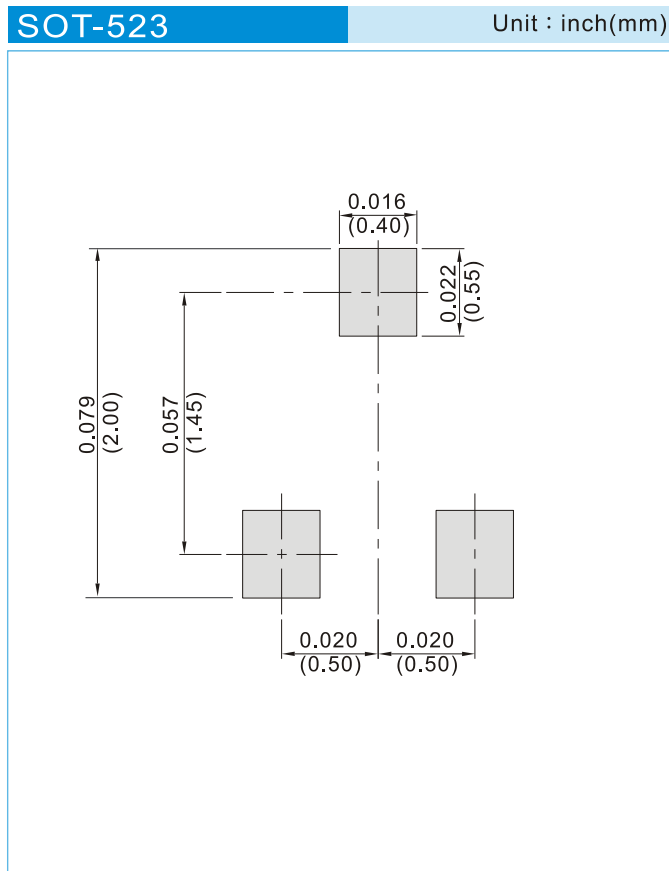


# PJE8408

## Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJE8408_R1_00001	SOT-523	4K pcs / 7" reel	E08	Halogen free RoHS compliant

## Mounting Pad Layout





## **PJE8408**

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